现货库存、技术资料、百科信息、热点资讯，精彩尽在鼎好！

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

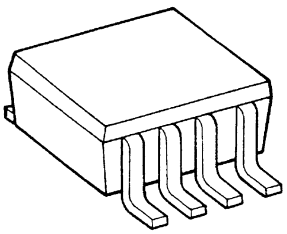
TC7WG04FU,TC7WG04FK

Triple Inverter

Features

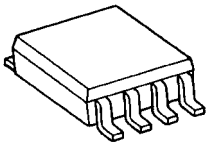
- High-level output current: I_{OH}/I_{OL} = ±8 mA (min) at V_{CC} = 3 V
- High-speed operation: t_{pd} = 2.7 ns (typ.) at V_{CC} = 3.3 V,15pF
- Operating voltage range: V_{CC} = 0.9~3.6 V
- 5.5-V tolerant inputs
- 3.6-V power down protection outputs

TC7WG04FU



SSOP8-P-0.65

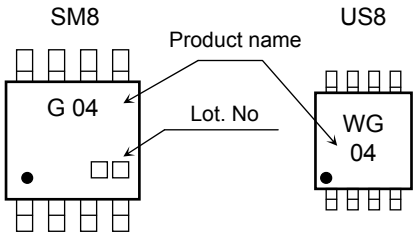
TC7WG04FK



SSOP8-P-0.50A

Weight
SSOP8-P-0.65 : 0.02 g (typ.)
SSOP8-P-0.50A : 0.01 g (typ.)

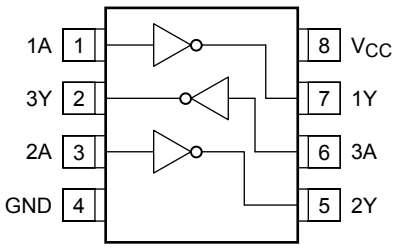
Marking



Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Value	Unit
Power supply voltage	V_{CC}	−0.5~4.6	V
DC input voltage	V_{IN}	−0.5~7.0	V
DC output voltage	V_{OUT}	−0.5~4.6 (Note 1)	V
		−0.5~V_{CC} + 0.5 (Note 2)	
Input diode current	I_{IK}	−20	mA
Output diode current	I_{OK}	−20 (Note 3)	mA
DC output current	I_{OUT}	±25	mA
DC V_{CC} / ground current	I_{CC}	±50	mA
Power dissipation	P_D	300 (SM8) 200 (US8)	mW
Storage temperature	T_{stg}	−65~150	°C

Pin Assignment (top view)



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: V_{CC} = 0V

Note 2: High or Low State. I_{OUT} absolute maximum rating must be observed.

Note 3: V_{OUT} < GND

IEC Logic Symbol

Truth Table

A	Y
L	H
H	L

Operating Ranges

Characteristics	Symbol	Value		Unit
Power supply voltage	V_{CC}	0.9~3.6		V
Input voltage	V_{IN}	0~5.5		V
Output voltage	V_{OUT}	0~3.6	(Note 4)	V
		0~V_{CC}	(Note 5)	
Output Current	I_{OH}/I_{OL}	±8.0	(Note 6)	mA
		±4.0	(Note 7)	
		±3.0	(Note 8)	
		±1.7	(Note 9)	
		±0.3	(Note 10)	
		±0.02	(Note 11)	
Operating temperature	T_{opr}	−40~85		°C
Input rise and fall time	dt/dV	0~10	(Note 12)	ns/V

Note 4: V_{CC} = 0V

Note 5: High or Low state

Note 6: V_{CC} = 3.0~3.6 V

Note 7: V_{CC} = 2.3~2.7 V

Note 8: V_{CC} = 1.65~1.95 V

Note 9: V_{CC} = 1.4~1.6 V

Note 10: V_{CC} = 1.1~1.3 V

Note 11: V_{CC} = 0.9 V

Note 12: V_{IN} = 0.8~2.0 V, V_{CC} = 3.0 V

Electrical Characteristics

DC Characteristics

Characteristics		Symbol	Test Condition		Ta = 25°C			Ta = −40~85°C		Unit
				V_{CC} (V)	Min	Typ.	Max	Min	Max	
Input voltage	High level	V_{IH}	—	0.9	V_{CC}	—	—	V_{CC}	—	V
				1.1~1.3	V_{CC} × 0.7	—	—	V_{CC} × 0.7	—	
				1.4~1.6	V_{CC} × 0.65	—	—	V_{CC} × 0.65	—	
				1.65~1.95	V_{CC} × 0.65	—	—	V_{CC} × 0.65	—	
				2.3~2.7	1.7	—	—	1.7	—	
				3.0~3.6	2.0	—	—	2.0	—	
	Low level	V_{IL}	—	0.9	—	—	GND	—	GND	
				1.1~1.3	—	—	V_{CC} × 0.3	—	V_{CC} × 0.3	
				1.4~1.6	—	—	V_{CC} × 0.35	—	V_{CC} × 0.35	
				1.65~1.95	—	—	V_{CC} × 0.35	—	V_{CC} × 0.35	
				2.3~2.7	—	—	0.7	—	0.7	
				3.0~3.6	—	—	0.8	—	0.8	
Output voltage	High level	V_{OH}	V_{IN} = V_{IL}	I_{OH} =−0.02 mA	0.9	0.75	—	—	0.75	—	V
				I_{OH} = −0.3 mA	1.1~1.3	V_{CC} × 0.75	—	—	V_{CC} × 0.75	—	
				I_{OH} = −1.7 mA	1.4~1.6	V_{CC} × 0.75	—	—	V_{CC} × 0.75	—	
				I_{OH} = −3.0 mA	1.65~1.95	V_{CC} -0.45	—	—	V_{CC} -0.45	—	
				I_{OH} = −4.0 mA	2.3~2.7	2.0	—	—	2.0	—	
				I_{OH} = −8.0 mA	3.0~3.6	2.48	—	—	2.48	—	
	Low level	V_{OL}	V_{IN} = V_{IH}	I_{OL} = 0.02 mA	0.9	—	—	0.1	—	0.1	
				I_{OL} = 0.3 mA	1.1~1.3	—	—	V_{CC} × 0.25	—	V_{CC} × 0.25	
				I_{OL} = 1.7 mA	1.4~1.6	—	—	V_{CC} × 0.25	—	V_{CC} × 0.25	
				I_{OL} = 3.0 mA	1.65~1.95	—	—	0.45	—	0.45	
				I_{OL} = 4.0 mA	2.3~2.7	—	—	0.4	—	0.4	
				I_{OL} = 8.0 mA	3.0~3.6	—	—	0.4	—	0.4	
Input leakage current		I_{IN}	V_{IN} = 0~5.5V		0~3.6	—	—	±0.1	—	±1.0	μA
Power off leakage current		I_{OFF}	V_{IN} = 0~5.5V V_{OUT} = 0~3.6V		0	—	—	1.0	—	10.0	μA
Quiescent supply current		I_{CC}	V_{IN} = V_{CC} or GND		3.6	—	—	1.0	—	10.0	μA

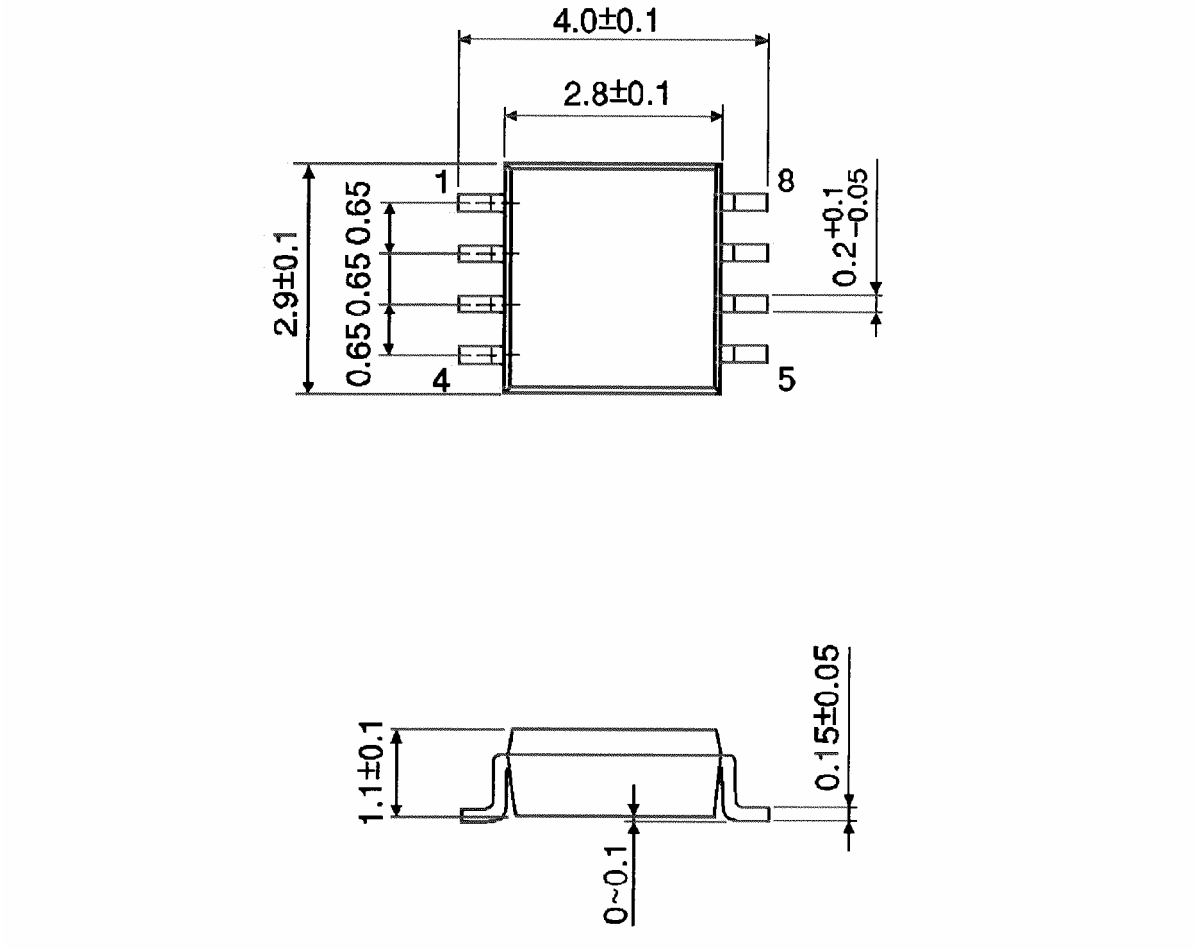
AC Characteristics (Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = −40~85°C		Unit
			V_{CC} (V)	Min	Typ.	Max	Min	Max	
Propagation delay time	t_{pLH} t_{pHL}	C_L = 10 pF, R_L = 1 MΩ	0.9	—	24.4	—	—	—	ns
			1.1~1.3	—	11.6	21.7	1.0	40.5	
			1.4~1.6	—	6.5	9.8	1.0	11.6	
			1.65~ 1.95	—	4.9	7.0	1.0	7.6	
			2.3~2.7	—	3.2	4.4	1.0	4.9	
			3.0~3.6	—	2.4	3.5	1.0	4.1	
		C_L = 15 pF, R_L = 1 MΩ	0.9	—	26.9	—	—	—	
			1.1~1.3	—	12.7	24.2	1.0	42.1	
			1.4~1.6	—	7.1	10.7	1.0	12.9	
			1.65~ 1.95	—	5.3	7.5	1.0	7.7	
			2.3~2.7	—	3.5	4.8	1.0	5.5	
			3.0~3.6	—	2.7	3.8	1.0	4.4	
		C_L = 30 pF, R_L = 1 MΩ	0.9	—	37.0	—	—	—	
			1.1~1.3	—	17.1	33.9	1.0	64.1	
			1.4~1.6	—	9.3	14.3	1.0	17.4	
			1.65~ 1.95	—	6.9	9.8	1.0	10.2	
			2.3~2.7	—	4.6	6.2	1.0	6.6	
			3.0~3.6	—	3.7	4.8	1.0	5.2	
Input capacitance	C_{IN}	—	3.6	—	3	—	—	—	pF
Power dissipation capacitance	C_{PD}	(Note 13)	0.9 ~ 3.6	—	10	—	—	—	pF

Note 13: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.
Average operating current can be obtained by the equation:
$I_{CC\ (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/3$

Package Dimensions

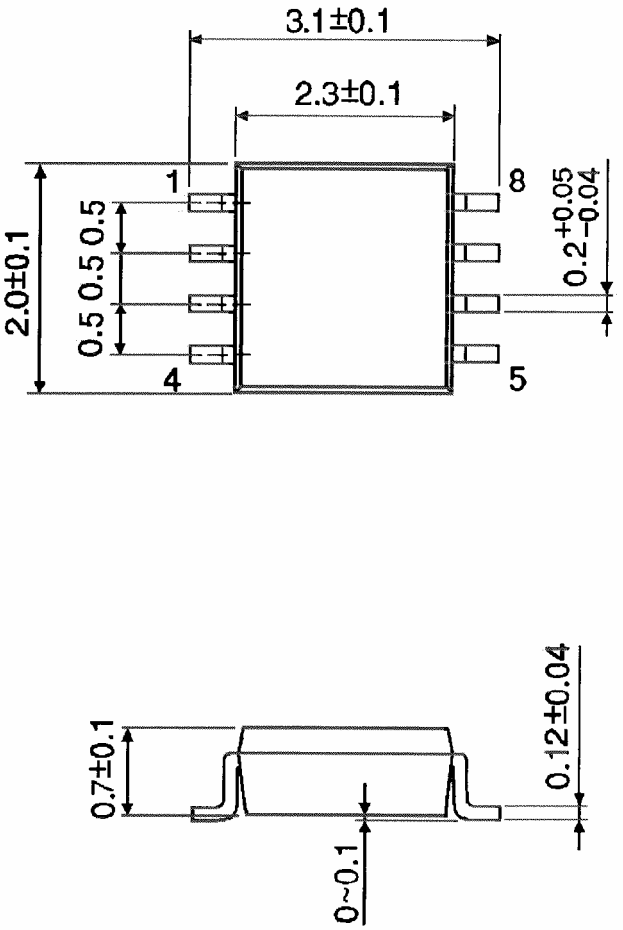
SSOP8-P-0.65 Unit : mm



Weight: 0.02 g (typ.)

Package Dimensions

SSOP8-P-0.50A Unit : mm



Weight: 0.01 g (typ.)

RESTRICTIONS ON PRODUCT USE

20070701-EN GENERAL

- The information contained herein is subject to change without notice.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
  In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the “Handling Guide for Semiconductor Devices,” or “TOSHIBA Semiconductor Reliability Handbook” etc.
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.).These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury (“Unintended Usage”). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in his document shall be made at the customer’s own risk.
- The products described in this document shall not be used or embedded to any downstream products of which manufacture, use and/or sale are prohibited under any applicable laws and regulations.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patents or other rights of TOSHIBA or the third parties.
- Please contact your sales representative for product-by-product details in this document regarding RoHS compatibility. Please use these products in this document in compliance with all applicable laws and regulations that regulate the inclusion or use of controlled substances. Toshiba assumes no liability for damage or losses occurring as a result of noncompliance with applicable laws and regulations.